

P-Channel 30 V (D-S) MOSFET

PowerPAK® SC-70-6L Single


FEATURES

- TrenchFET® Gen IV p-channel power MOSFET
- Thermally enhanced PowerPAK® SC-70 package
- Very low $R_{DS(on)}$ x area minimizes power loss on limited PCB real estate
- Provides excellent $R_{DS}-Q_g$ Figure-of-Merit (FOM) for switching applications
- 100 % R_g tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT
HALOGEN
FREE

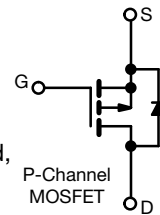
PRODUCT SUMMARY

V_{DS} (V)	-30
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -10$ V	0.0140
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -4.5$ V	0.0241
Q_g typ. (nC)	8.9
I_D (A)	-30.3
Configuration	Single

Marking code: B9

APPLICATIONS

- Battery charging and management
- Load switch
- DC/DC converters
- Power management in battery-operated, mobile and wearable devices



ORDERING INFORMATION

Package	PowerPAK SC-70
Lead (Pb)-free and halogen-free	SiA471DJ-T1-GE3

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	V_{DS}	-30	V
Gate-source voltage	V_{GS}	-20 / +16	V
Continuous drain current ($T_J = 150$ °C)	I_D	$T_C = 25$ °C	-30.3
		$T_C = 70$ °C	-24.2
		$T_A = 25$ °C	-12.9 ^{a, b}
		$T_A = 70$ °C	-10.3 ^{a, b}
Pulsed drain current ($t = 100$ μ s)	I_{DM}	-70	A
Continuous source-drain diode current	I_S	$T_C = 25$ °C	-16
		$T_A = 25$ °C	-2.9 ^{a, b}
Maximum power dissipation	P_D	$T_C = 25$ °C	19.2
		$T_C = 70$ °C	12.3
		$T_A = 25$ °C	3.5 ^{a, b}
		$T_A = 70$ °C	2.2 ^{a, b}
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +150	°C
Soldering recommendations (peak temperature) ^{c, d}		260	°C

THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^{a, e}	R_{thJA}	28	36	°C/W
Maximum junction-to-case (drain)	R_{thJC}	5.3	6.5	

Notes

- Surface mounted on 1" x 1" FR4 board
- $t = 5$ s
- See solder profile (www.vishay.com/ppg?73257). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
- Maximum under steady state conditions is 80 °C/W



SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0\text{ V}$, $I_D = -250\text{ }\mu\text{A}$	-30	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	$I_D = -10\text{ mA}$	-	-15	-	mV/ $^\circ\text{C}$
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$		-	5	-	
Gate-source threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250\text{ }\mu\text{A}$	-1	-	-2.5	V
Gate-source leakage	I_{GSS}	$V_{DS} = 0\text{ V}$, $V_{GS} = -20\text{ V} / +16\text{ V}$	-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -30\text{ V}$, $V_{GS} = 0\text{ V}$	-	-	-1	μA
		$V_{DS} = -30\text{ V}$, $V_{GS} = 0\text{ V}$, $T_J = 55\text{ }^\circ\text{C}$	-	-	-10	
On-state drain current ^a	$I_{D(on)}$	$V_{DS} \leq -5\text{ V}$, $V_{GS} = 0\text{ V}$	-10	-	-	A
Drain-source on-state resistance ^a	$R_{DS(on)}$	$V_{GS} = -10\text{ V}$, $I_D = -10\text{ A}$	-	0.0115	0.0140	Ω
		$V_{GS} = -4.5\text{ V}$, $I_D = -7\text{ A}$	-	0.0185	0.0241	
Forward transconductance ^a	g_{fs}	$V_{DS} = -10\text{ V}$, $I_D = -10\text{ A}$	-	40	-	S
Dynamic ^b						
Input capacitance	C_{ISS}	$V_{DS} = -15\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	-	1170	-	pF
Output capacitance	C_{OSS}		-	570	-	
Reverse transfer capacitance	C_{rss}		-	55	-	
Total gate charge	Q_g	$V_{DS} = -15\text{ V}$, $V_{GS} = -10\text{ V}$, $I_D = -12\text{ A}$	-	18.5	27.8	nC
		$V_{DS} = -15\text{ V}$, $V_{GS} = -4.5\text{ V}$, $I_D = -12\text{ A}$	-	8.9	14	
Gate-source charge	Q_{gs}	$V_{DS} = -15\text{ V}$, $V_{GS} = -4.5\text{ V}$, $I_D = -12\text{ A}$	-	4.4	-	nC
Gate-drain charge	Q_{gd}		-	2.7	-	
Gate resistance	R_g	$f = 1\text{ MHz}$	0.22	11	22	Ω
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -15\text{ V}$, $R_L = 1.5\text{ }\Omega$, $I_D \cong -10\text{ A}$, $V_{GEN} = -4.5\text{ V}$, $R_g = 1\text{ }\Omega$	-	25	50	ns
Rise time	t_r		-	95	190	
Turn-off delay time	$t_{d(off)}$		-	40	80	
Fall time	t_f		-	18	36	
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -15\text{ V}$, $R_L = 1.5\text{ }\Omega$, $I_D \cong -10\text{ A}$, $V_{GEN} = -10\text{ V}$, $R_g = 1\text{ }\Omega$	-	13	26	
Rise time	t_r		-	8	16	
Turn-off delay time	$t_{d(off)}$		-	35	70	
Fall time	t_f		-	15	30	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I_S	$T_C = 25\text{ }^\circ\text{C}$	-	-	-16	A
Pulse diode forward current	I_{SM}		-	-	-70	
Body diode voltage	V_{SD}	$I_S = -10\text{ A}$, $V_{GS} = 0\text{ V}$	-	-0.85	-1.2	V
Body diode reverse recovery time	t_{rr}	$I_F = -10\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$, $T_J = 25\text{ }^\circ\text{C}$	-	21	42	ns
Body diode reverse recovery charge	Q_{rr}		-	8	16	nC
Reverse recovery fall time	t_a		-	9	-	ns
Reverse recovery rise time	t_b		-	12	-	

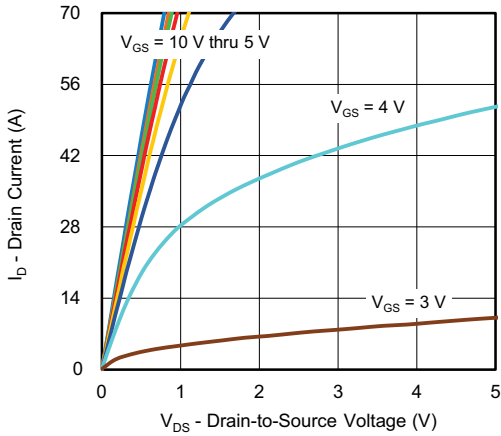
Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing

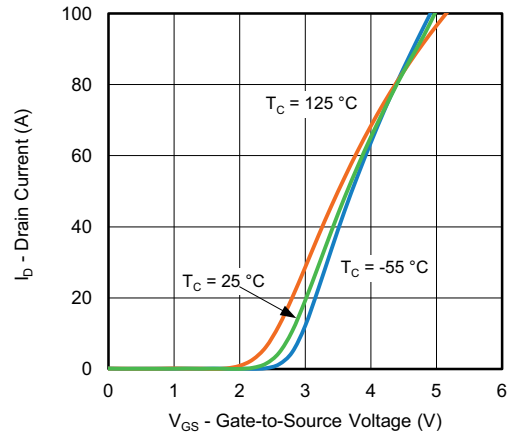
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



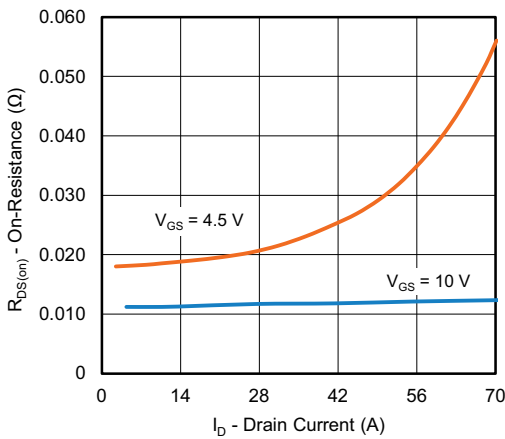
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



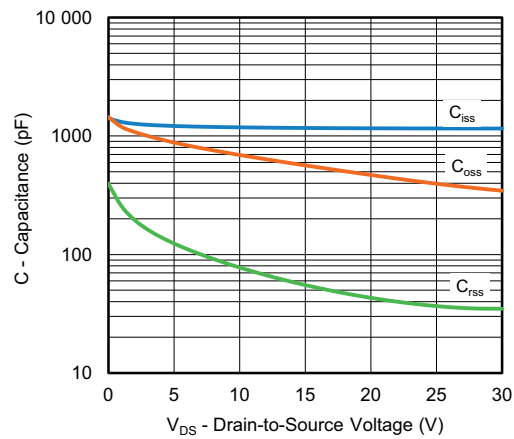
Output Characteristics



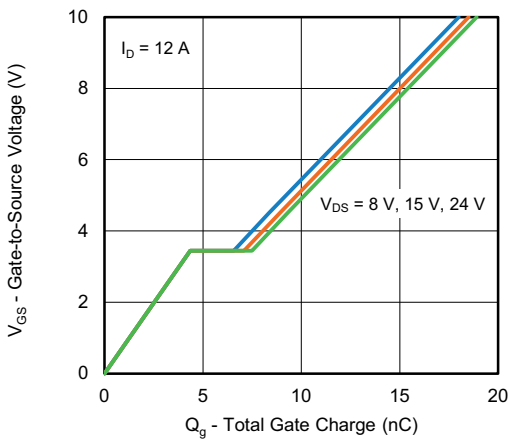
Transfer Characteristics



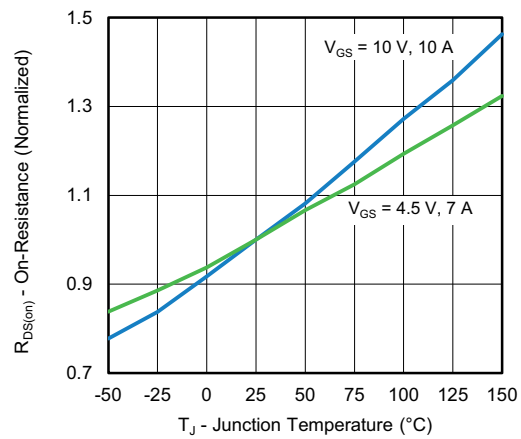
On-Resistance vs. Drain Current and Gate Voltage



Capacitance



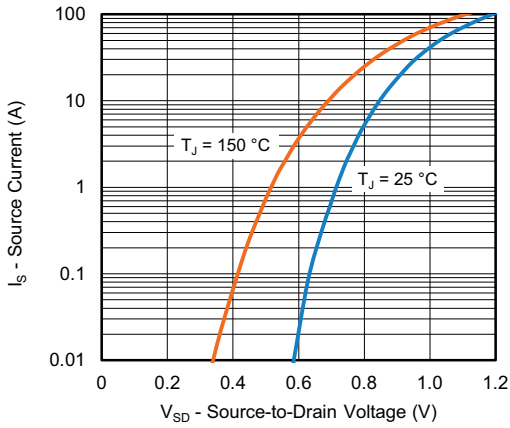
Gate Charge



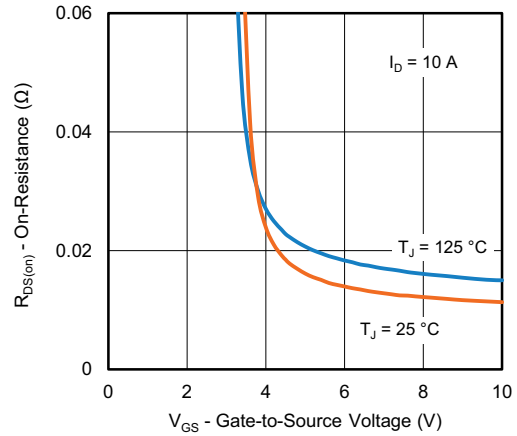
On-Resistance vs. Junction Temperature



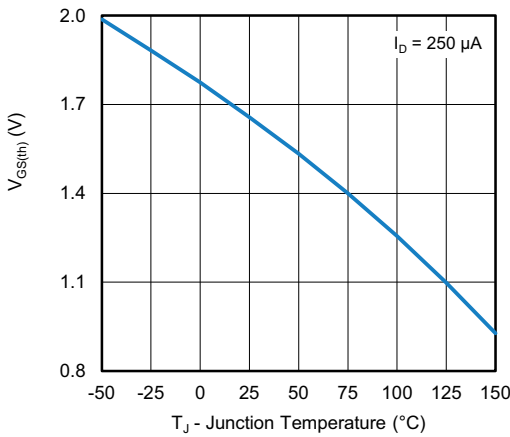
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



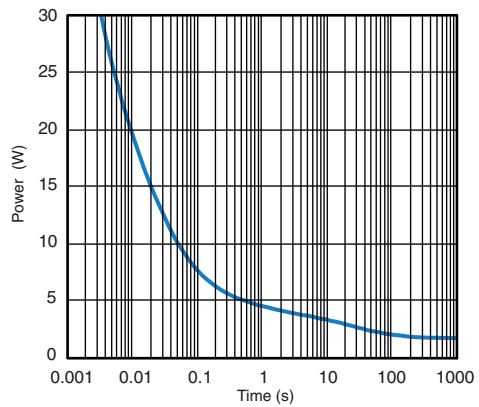
Source-Drain Diode Forward Voltage



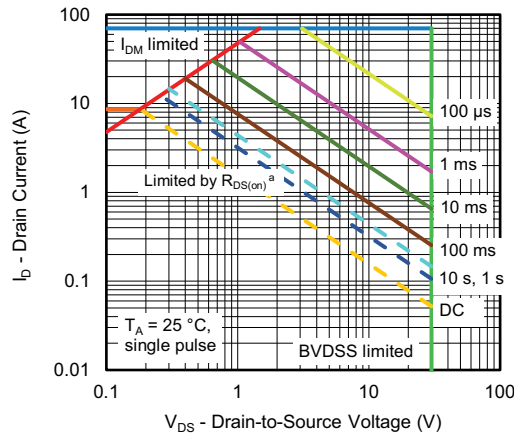
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



Single Pulse Power, Junction-to-Ambient



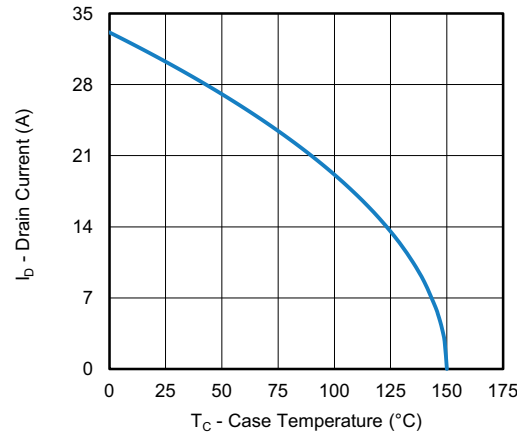
Safe Operating Area, Junction-to-Ambient

Note

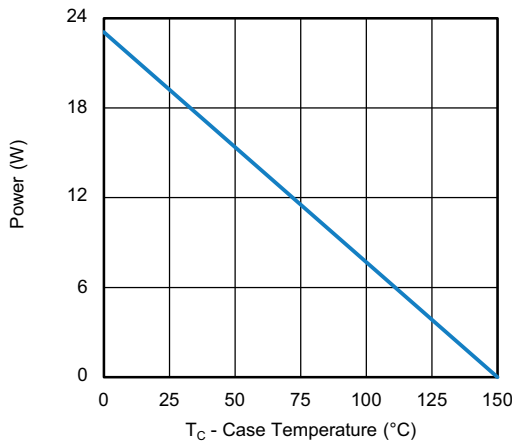
a. VGS > minimum VGS at which RDS(on) is specified



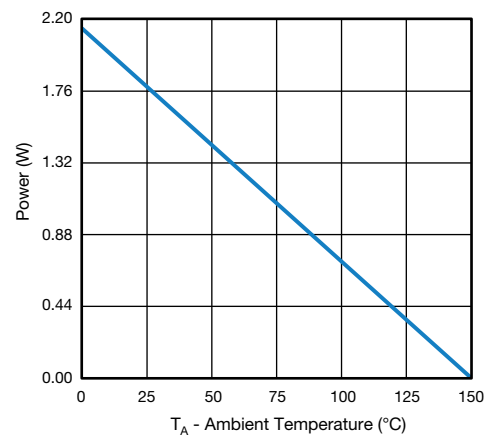
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating ^a



Power, Junction-to-Case

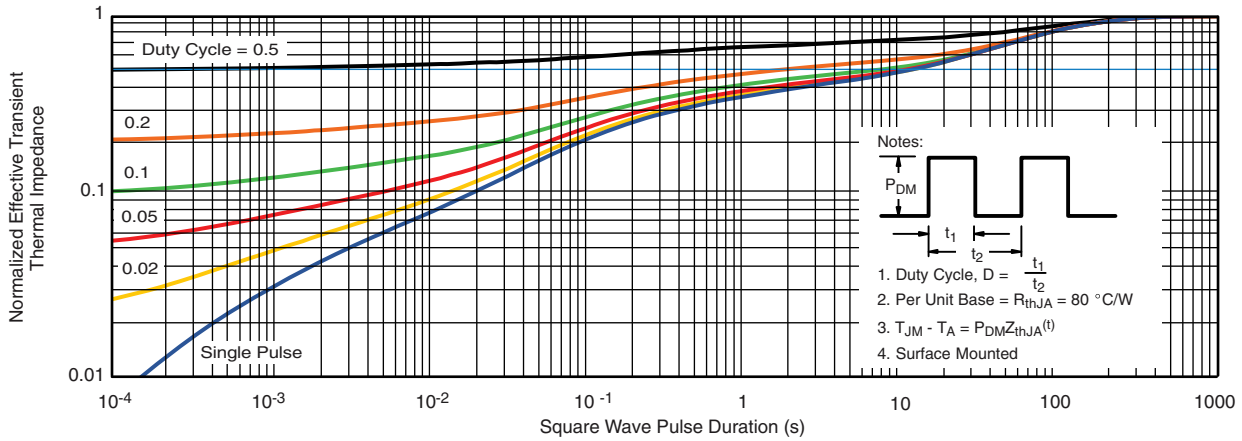


Power, Junction-to-Ambient

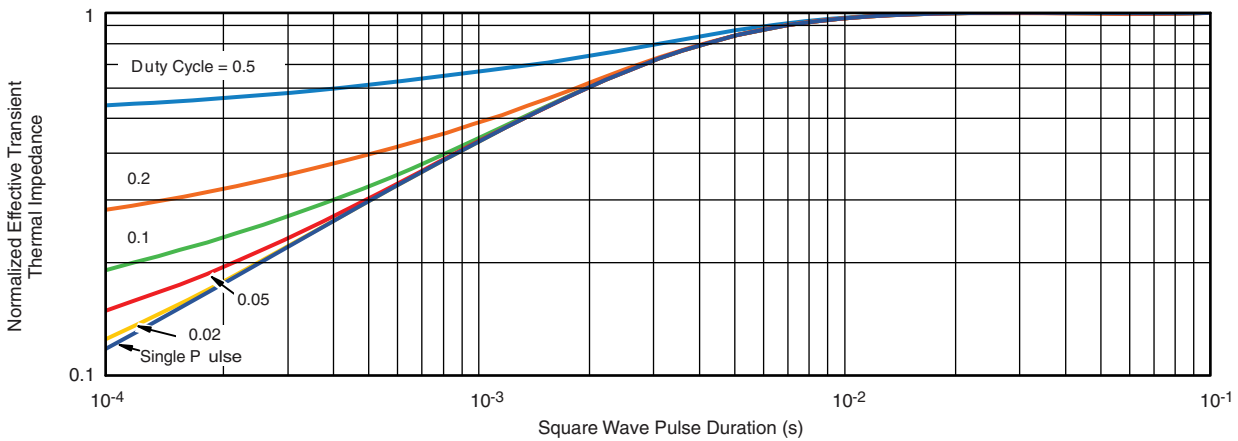
Note

- a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-ambient thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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